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L. Spruell

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Patent Application of  
Zhijun Qu and Kenneth Wagers

New York, New York

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Serial No.: 09/329,156

Group Art Unit: 2811

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For: DUAL EPITAXIAL LAYER FOR HIGH VOLTAGE VERTICAL  
CONDUCTION POWER MOSFET DEVICES

Assistant Commissioner for Patents  
Washington, D.C. 20231

INFORMATION DISCLOSURE STATEMENT

Sir:

Submitted herewith is a copy of art together with a form listing the same  
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Respectfully submitted,

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